

## Electronic Patent Application Fee Transmittal

**Application Number:**

**Filing Date:**

**Title of Invention:**

Method of Forming Thin SGOI Wafers with High Relaxation and Low Stacking Fault Defect Density

**First Named Inventor:**

Huajie Chen

**Filer:**

Yuanmin Cai

**Attorney Docket Number:**

FIS920030342US1

Filed as Large Entity

### U.S. National Stage under 35 USC 371 Filing Fees

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
<b>Basic Filing:</b>				
National Stage Fee	1631	1	300	300
Natl Stage Search - U.S. as IPE or ISA	1640	1	0	0
National Stage Exam Fee - U.S. was IPEA	1643	1	0	0

**Pages:**

**Claims:**

**Miscellaneous-Filing:**

**Petition:**

**Patent-Appeals-and-Interference:**

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Post-Allowance-and-Post-Issuance:				
Extension-of-Time:				
Miscellaneous:				
Total in USD (\$)				300